

 GENERAL SEMICONDUCTOR® **UG18CT, UGF18CT, UGB18CT Series**
Dual Ultrafast Plastic Rectifiers

Maximum Ratings ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	UG18ACT	UG18BCT	UG18CCT	UG18DCT	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V
Maximum average forward rectified current at $T_C = 105^\circ\text{C}$	$I_F(AV)$	18				A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) per leg	I_{FSM}	175				A
Operating junction and storage temperature range	T_J, T_{STG}	-65 to $+150$				$^\circ\text{C}$
RMS Isolation voltage (UGF) from terminals to heatsink with $t = 1.0$ second, $RH \leq 30\%$	V_{ISOL}	4500 ⁽¹⁾ 3500 ⁽²⁾ 1500 ⁽³⁾				V

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	UG18ACT	UG18BCT	UG18CCT	UG18DCT	Unit
Maximum instantaneous forward voltage ⁽⁴⁾ at 9.0A 20A 5.0A, $T_J = 100^\circ\text{C}$	V_F	1.1 1.2 0.95				V
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage per leg $T_A = 100^\circ\text{C}$	I_R	10 300				μA
Maximum reverse recovery time per leg at $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$	t_{rr}	20				ns
Maximum reverse recovery time per leg at $T_J = 25^\circ\text{C}$ $I_F = 9.0\text{A}$, $V_R = 30\text{V}$, $di/dt = 50\text{A}/\mu\text{s}$, $I_{rr} = 10\% I_{RM}$ $T_J = 100^\circ\text{C}$	t_{rr}	30 50				ns
Maximum stored charge per leg $T_J = 25^\circ\text{C}$ $I_F = 9.0\text{A}$, $V_R = 30\text{V}$, $di/dt = 50\text{A}/\mu\text{s}$, $I_{rr} = 10\% I_{RM}$ $T_J = 100^\circ\text{C}$	Q_{rr}	20 45				nC
Typical junction capacitance per leg at 4.0V, 1MHz	C_J	30				pF

Thermal Characteristics ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	UG18	UGF18	UGB18	Unit
Typical thermal resistance from junction to case per leg	$R_{\theta JC}$	4.0	6.0	4.0	$^\circ\text{C}/\text{W}$

Notes:

- (1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
(2) Clip mounting (on case), where leads do overlap heatsink
(3) Screw mounting with 4-40 screw, where washer diameter is $\leq 4.9\text{mm}$ (0.19")
(4) Pulse test: 300 μs pulse width, 1% duty cycle

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Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

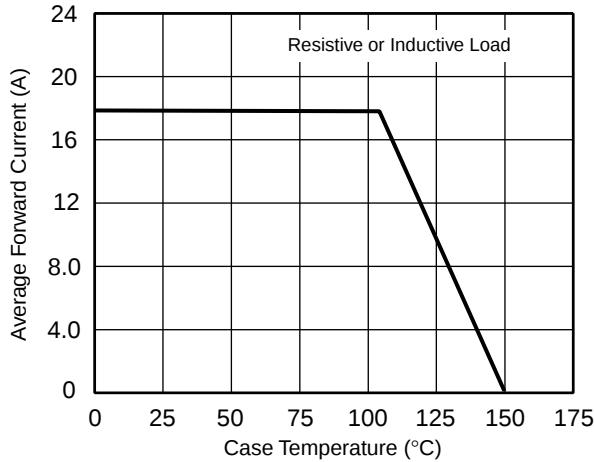


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current Per Leg

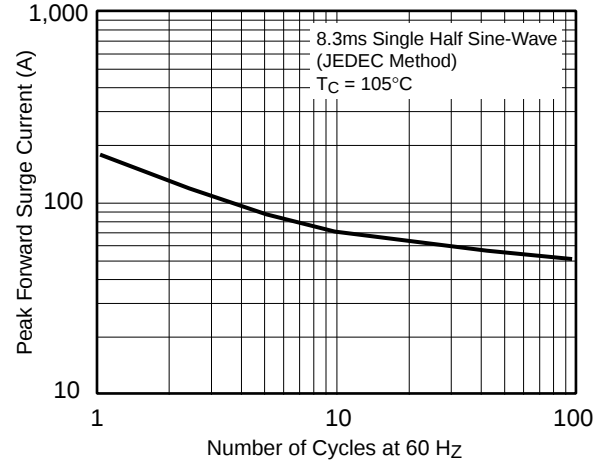


Fig. 3 – Typical Instantaneous Forward Characteristics Per Leg

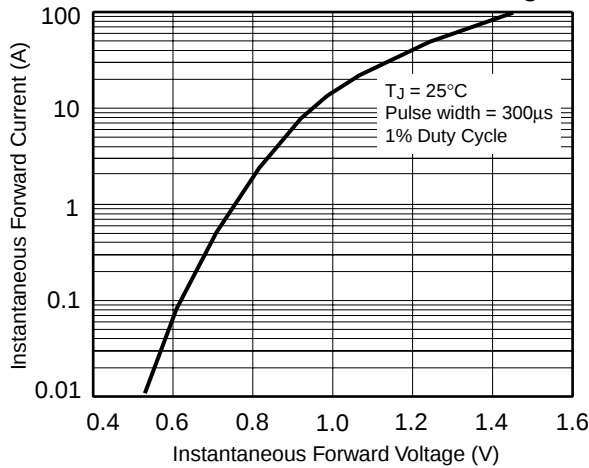


Fig. 4 – Typical Reverse Leakage Characteristics Per Leg

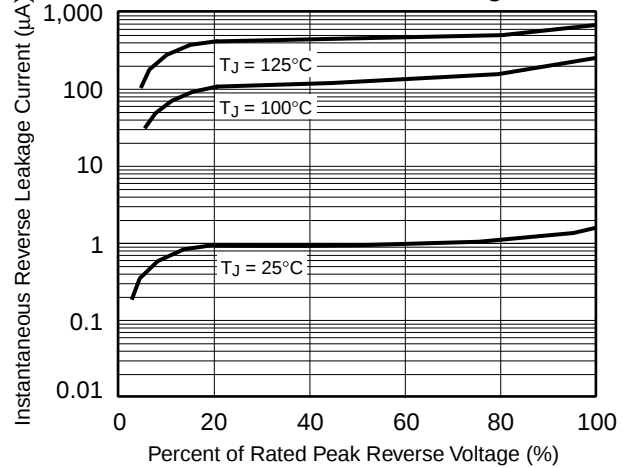


Fig. 5 – Reverse Switching Characteristics Per Leg

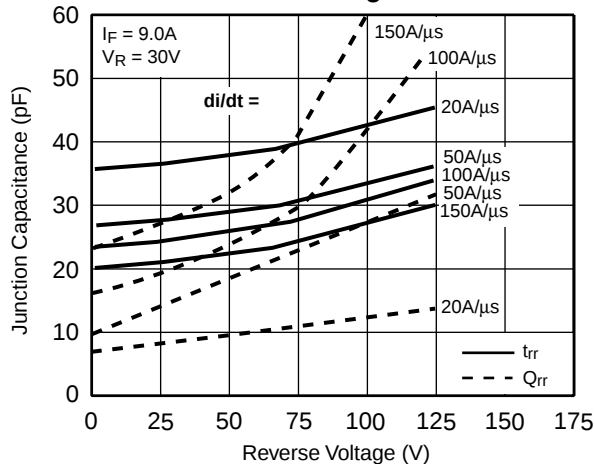


Fig. 6 – Typical Junction Capacitance Per Leg

